

DATASHEET

1.9mm Round Subminiature" Z-Bend" Lead Photodiode PD95-21B/TR10



Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Compatible with infrared and vapor phase reflow solder process.
- Pb free
- The product itself will remain within RoHS compliant version.
- Compliance with EU REACH.
- Compliance Halogen Free .(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm).

Descriptions

• PD95-21B/TR10 is a high speed and high sensitive PIN photodiode in miniature top view lens SMD package and it is molded in a black plastic .The device is spectrally matched with the infrared emitting diode.

Applications

- Infrared applied system
- Copier
- Sensor in automotive project

Device Selection Guide

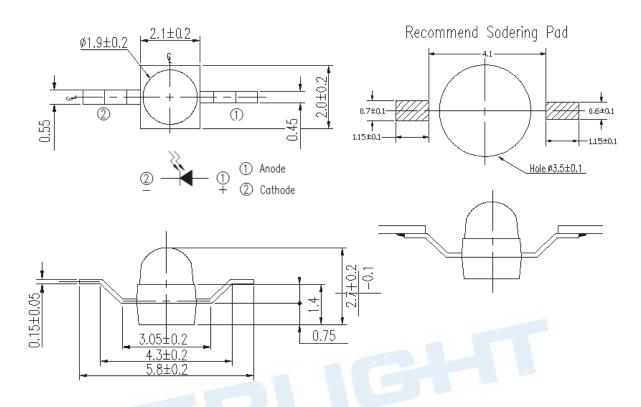
Part Category	Chip Material	Lens Color
PD	Silicon	Black

Ver.:5 Release Date:10/26/2021

狀態:Approved(正式發行)



Package Dimensions



Notes: 1.All dimensions are in millimeters

2.Tolerances unless dimensions ±0.1mm



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Symbol Rating	
Reverse Voltage	V_R 32		V
Operating Temperature	T_{opr}	-25 ~ +85	$^{\circ}\!\mathbb{C}$
Storage Temperature	T_{stg}	-40 ~ +85	$^{\circ}\!\mathbb{C}$
Soldering Temperature *1	T_{sol}	260	$^{\circ}\!\mathbb{C}$
Power Dissipation at(or below)	P_d	150	mW
25°C Free Air Temperature			

Notes: *1:Soldering time \leq 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Rang of Spectral Bandwidth	λ 0.5		730		1100	nm
Wavelength of Peak Sensitivity	λр	11-65		940		nm
Short-Circuit Current	I_{SC}	Ee=1mW/cm ² λ p=875nm		4		μΑ
Reverse Light Current	I_L	$Ee=1mW/cm^{2}$ $\lambda p=875nm$ $V_{R}=5V$	1	4		μΑ
Reverse Dark Current	I_D	Ee=0mW/cm ² V _R =10V			10	nA
Reverse Breakdown Voltage	V_{BR}	Ee=0mW/cm ² I_R =100 μ A	32	170		V



Typical Electro-Optical Characteristics Curves

Fig.1 Spectral Sensitivity

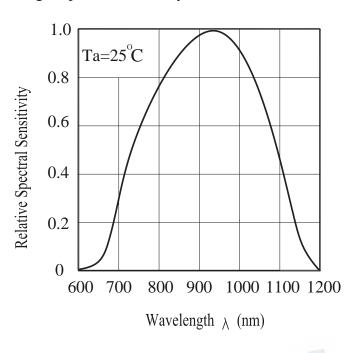
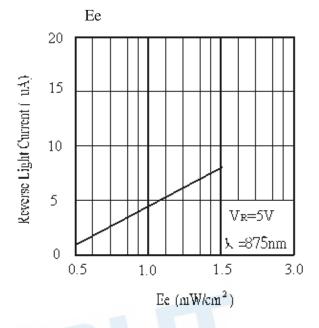


Fig.2 Reverse Light Current vs.





Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

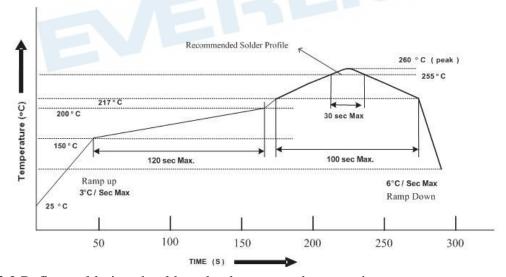
2. Storage

- 2.1 Do not open moisture proof bag before the products are ready to use.
- 2.2 Before opening the package, the Photodiode should be kept at 30℃ or less and 90%RH or less.
- 2.3 The Photodiode should be used within a year.
- 2.4 After opening the package, the Photodiode should be kept at 30°C or less and 70%RH or less.
- 2.5 The Photodiode should be used within 168 hours (7 days) after opening the package.
- 2.6 If the moisture absorbent material (silica gel) has faded away or the Photodiode have exceeded the storage time, baking treatment should be performed using the following conditions.

 Baking treatment: 60±5°C for 24 hours.

3. Soldering Condition

3.1 Pb-free solder temperature profile



- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the Photodiode during heating.
- 3.4 After soldering, do not warp the circuit board.

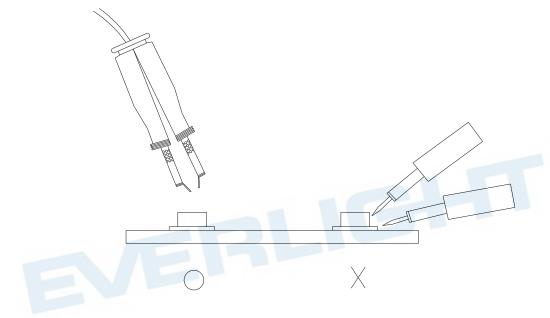


4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 350° C for 3 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

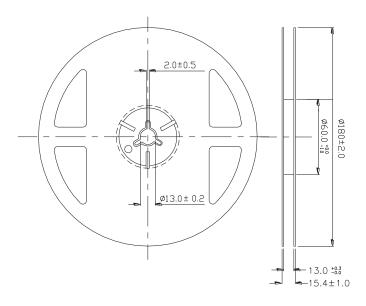
5.Repairing

Repair should not be done after the Photodiode have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the Photodiode will or will not be damaged by repairing.



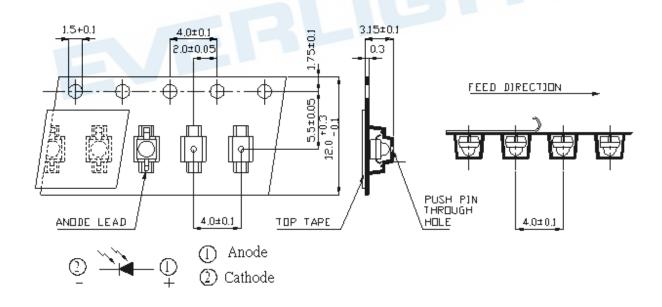


Package Dimensions



Note: The tolerances unless mentioned are ± 0.1 , unit=mm.

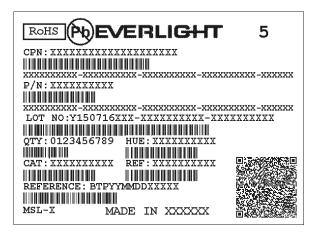
Carrier Tape Dimensions: (Quantity: 1000PCS/Reel)



Note: The tolerances unless mentioned are ± 0.1 , unit=mm.



Label Form Specification



CPN: Customer's Production Number

P/N: Production Number QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number MSL-X: MSL Level

Made In: Manufacture place

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. The graphs shown in this datasheet are representing typical data only and do not show quaranteed values.
- 3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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- 5. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized Everlight sales agent for special application request.

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